

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074



ON Semiconductor®

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## Operational Amplifier, Rail-to-Rail Output, 3 MHz BW

The NCx2007x series operational amplifiers provide rail-to-rail output operation, 3 MHz bandwidth, and are available in single, dual, and quad configurations. Rail-to-rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The NCx2007x can operate on supply voltages as low as 2.7 V over the temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . At a 2.7 V supply, the high bandwidth provides a slew rate of  $2.8\text{ V}/\mu\text{s}$  while only consuming  $405\ \mu\text{A}$  of quiescent current per channel. The wide supply range allows the NCx2007x to run on supply voltages as high as 36 V, making it ideal for a broad range of applications. Since this is a CMOS device, high input impedance and low bias currents make it ideal for interfacing to a wide variety of signal sensors. The NCx2007x devices are available in a variety of compact packages. Automotive qualified options are available under the NCV prefix.

### Features

- Rail-To-Rail Output
- Wide Supply Range: 2.7 V to 36 V
- Wide Bandwidth: 3 MHz typical at  $V_S = 2.7\text{ V}$
- High Slew Rate:  $2.8\text{ V}/\mu\text{s}$  typical at  $V_S = 2.7\text{ V}$
- Low Supply Current:  $405\ \mu\text{A}$  per channel at  $V_S = 2.7\text{ V}$
- Low Input Bias Current: 5 pA typical
- Wide Temperature Range:  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$
- Available in a variety of packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Applications

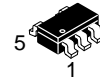
- Current Sensing
- Signal Conditioning
- Automotive

### End Products

- Notebook Computers
- Portable Instruments
- Power Supplies



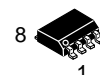
SOT-553  
CASE 463B



TSOP-5  
CASE 483



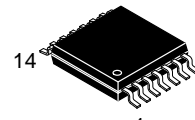
Micro8™  
CASE 846A



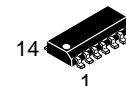
SOIC-8  
CASE 751



TSSOP-8  
CASE 948S



TSSOP-14  
CASE 948G



SOIC-14 NB  
CASE 751A

### DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 2 of this data sheet.

### ORDERING INFORMATION

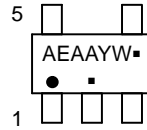
See detailed ordering and shipping information on page 4 of this data sheet.

MARKING DIAGRAMS

Single Channel Configuration  
NCS20071, NCV20071

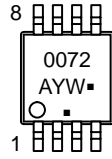


SOT-553  
CASE 463B

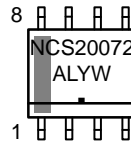


TSOP-5  
CASE 483

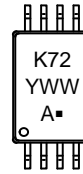
Dual Channel Configuration  
NCS20072, NCV20072



Micro8™  
CASE 846A

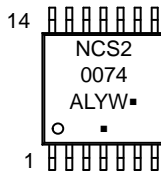


SOIC-8  
CASE 751

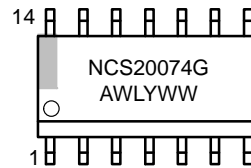


TSSOP-8  
CASE 948S

Quad Channel Configuration  
NCS20074, NCV20074



TSSOP-14  
CASE 948G



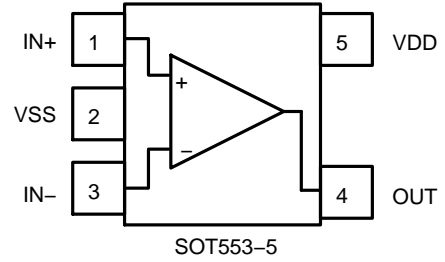
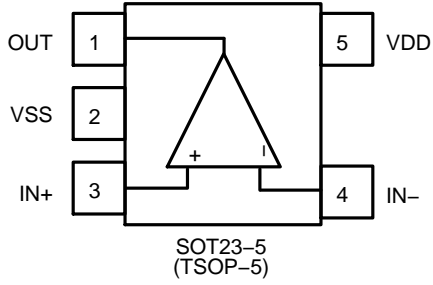
SOIC-14 NB  
CASE 751A

- XXXXX = Specific Device Code
- A = Assembly Location
- WL, L = Wafer Lot
- Y = Year
- WW, W = Work Week
- G or ■ = Pb-Free Package

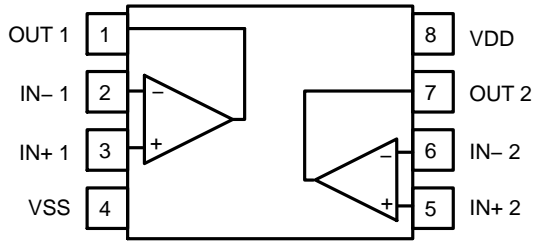
(Note: Microdot may be in either location)

**NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074**

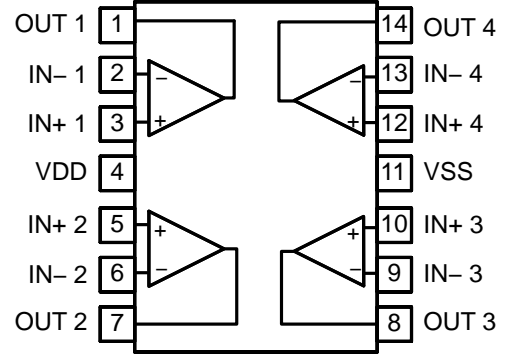
**Single Channel Configuration**  
NCS20071, NCV20071



**Dual Channel Configuration**  
NCS20072, NCV20072



**Quadruple Channel Configuration**  
NCS20074, NCV20074



**Figure 1. Pin Connections**

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ORDERING INFORMATION

Device	Configuration	Automotive	Marking	Package	Shipping†
NCS20071SN2T1G	Single	No	AEA	TSOP-5 (Pb-Free)	3000 / Tape and Reel
NCS20071XV53T2G			AL	SOT553-5 (Pb-Free)	4000 / Tape and Reel
NCV20071SN2T1G*		Yes	AEA	TSOP-5 (Pb-Free)	3000 / Tape and Reel
NCV20071XV53T2G*			AL	SOT553-5 (Pb-Free)	4000 / Tape and Reel
NCS20072DMR2G	Dual	No	0072	Micro8 (MSOP8) (Pb-Free)	4000 / Tape and Reel
NCS20072DR2G			NCS20072	SOIC-8 (Pb-Free)	2500 / Tape and Reel
NCS20072DTBR2G			K72	TSSOP-8 (Pb-Free)	2500 / Tape and Reel
NCV20072DMR2G*		Yes	0072	Micro8 (MSOP8) (Pb-Free)	4000 / Tape and Reel
NCV20072DR2G*			NCS20072	SOIC-8 (Pb-Free)	2500 / Tape and Reel
NCV20072DTBR2G*			K72	TSSOP-8 (Pb-Free)	2500 / Tape and Reel
NCS20074DR2G	Quad	No	NCS20074	SOIC-14 (Pb-Free)	2500 / Tape and Reel
NCS20074DTBR2G			NCS2 0074	TSSOP-14 (Pb-Free)	2500 / Tape and Reel
NCV20074DR2G*		Yes	NCS20074	SOIC-14 (Pb-Free)	2500 / Tape and Reel
NCV20074DTBR2G*			NCS2 0074	TSSOP-14 (Pb-Free)	2500 / Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Rating	Symbol	Limit	Unit	
Supply Voltage ( $V_{DD} - V_{SS}$ ) (Note 4)	$V_S$	40	V	
Input Voltage	$V_{CM}$	$V_{SS} - 0.2$ to $V_{DD} + 0.2$	V	
Differential Input Voltage (Note 2)	$V_{ID}$	$\pm V_S$	V	
Maximum Input Current	$I_{IN}$	$\pm 10$	mA	
Maximum Output Current (Note 3)	$I_O$	$\pm 100$	mA	
Continuous Total Power Dissipation (Note 4)	$P_D$	200	mW	
Maximum Junction Temperature	$T_J$	150	°C	
Storage Temperature Range	$T_{STG}$	-65 to 150	°C	
Mounting Temperature (Infrared or Convection – 20 sec)	$T_{mount}$	260	°C	
ESD Capability (Note 5)	Human Body Model	HBM	2000	V
	Machine Model – NCx20071	MM	200	
	Machine Model – NCx20072, NCx20074	MM	150	
	Charged Device Model – NCx20071, NCx20072	CDM	2000 (C6)	
	Charged Device Model – NCx20074	CDM	1000 (C6)	
Latch-Up Current (Note 6)	$I_{LU}$	100	mA	
Moisture Sensitivity Level (Note 7)	MSL	Level 1		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- Maximum input current must be limited to  $\pm 10$  mA. Series connected resistors of at least 500  $\Omega$  on both inputs may be used to limit the maximum input current to  $\pm 10$  mA.
- Total power dissipation must be limited to prevent the junction temperature from exceeding the 150°C limit.
- Continuous short circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of the maximum output current rating over the long term may adversely affect reliability. Shorting output to either VDD or VSS will adversely affect reliability.
- This device series incorporates ESD protection and is tested by the following methods:  
ESD Human Body Model tested per JEDEC standard JS-001 (AEC-Q100-002)  
ESD Machine Model tested per JEDEC standard JESD22-A115 (AEC-Q100-003)  
ESD Charged Device Model tested per JEDEC standard JESD22-C101 (AEC-Q100-011)
- Latch-up Current tested per JEDEC standard JESD78 (AEC-Q100-004)
- Moisture Sensitivity Level tested per IPC/JEDEC standard J-STD-020A

## THERMAL INFORMATION

Parameter	Symbol	Package	Single Layer Board (Note 8)	Multi-Layer Board (Note 9)	Unit
Junction-to-Ambient	$\theta_{JA}$	SOT23-5 / TSOP5	265	195	°C/W
		SOT553-5	325	244	
		Micro8 / MSOP8	236	167	
		SOIC-8	190	131	
		TSSOP-8	253	194	
		SOIC-14	142	101	
		TSSOP-14	179	128	

8. Values based on a 1S standard PCB according to JEDEC51-3 with 1.0 oz copper and a 300 mm<sup>2</sup> copper area

9. Values based on a 1S2P standard PCB according to JEDEC51-7 with 1.0 oz copper and a 100 mm<sup>2</sup> copper area

## OPERATING RANGES

Parameter	Symbol	Min	Max	Unit
Operating Supply Voltage (Single Supply)	$V_S$	2.7	36	V
Operating Supply Voltage (Split Supply)	$V_S$	$\pm 1.35$	$\pm 18$	V
Differential Input Voltage (Note 10)	$V_{ID}$		$V_S$	V
Input Common Mode Voltage Range	$V_{CM}$	$V_{SS}$	$V_{DD} - 1.35$	V
Ambient Temperature	$T_A$	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- Maximum input current must be limited to  $\pm 10$  mA. See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 2.7\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis.

**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 11, 12)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
<b>INPUT CHARACTERISTICS</b>							
Input Offset Voltage	$V_{OS}$	NCx20071			1.3	$\pm 3.5$	mV
						<b><math>\pm 4.5</math></b>	
		NCx20072, NCx20074			1.3	$\pm 3$	
						<b><math>\pm 4</math></b>	
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$			2		$\mu\text{V}/^\circ\text{C}$
Input Bias Current (Note 12)	$I_{IB}$				5	200	pA
						<b>1500</b>	
Input Offset Current (Note 12)	$I_{OS}$	NCx20071, NCx20072			2	75	pA
						<b>500</b>	
		NCx20074			2	75	
						<b>200</b>	
Channel Separation	XTLK	DC	NCx20072		100		dB
			NCx20074		115		
Differential Input Resistance	$R_{ID}$				5		$\text{G}\Omega$
Common Mode Input Resistance	$R_{IN}$				5		$\text{G}\Omega$
Differential Input Capacitance	$C_{ID}$				1.5		pF
Common Mode Input Capacitance	$C_{CM}$				3.5		pF
Common Mode Rejection Ratio	CMRR	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$			90	110	dB
					<b>69</b>		

## OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	$A_{VOL}$			96	118		dB
				<b>86</b>			
Output Current Capability (Note 13)	$I_O$	Op amp sinking current			70		mA
		Op amp sourcing current			50		
Output Voltage High	$V_{OH}$	Voltage output swing from positive rail			0.006	0.15	V
						<b>0.22</b>	
Output Voltage Low	$V_{OL}$	Voltage output swing from negative rail			0.005	0.15	V
						<b>0.22</b>	

## AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	$C_L = 25\text{ pF}$			3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20\text{ pF}$ , $R_L = 2\text{ k}\Omega$			2.8		$\text{V}/\mu\text{s}$
Phase Margin	$\varphi_m$	$C_L = 25\text{ pF}$			50		$^\circ$
Gain Margin	$A_m$	$C_L = 25\text{ pF}$			14		dB
Settling Time	$t_s$	$V_O = 1\text{ V}_{pp}$ , Gain = 1, $C_L = 20\text{ pF}$	Settling time to 0.1%		0.6		$\mu\text{s}$
			Settling time to 0.01%		1.2		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

11. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

12. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

13. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 2.7\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis.

**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 11, 12)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>NOISE CHARACTERISTICS</b>						
Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 0.5\text{ V}_{pp}$ , $f = 1\text{ kHz}$ , $A_v = 1$		0.05		%
Input Referred Voltage Noise	$e_n$	$f = 1\text{ kHz}$		30		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		20		
Input Referred Current Noise	$i_n$	$f = 1\text{ kHz}$		90		$\text{fA}/\sqrt{\text{Hz}}$

## SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No Load		114	135		dB
				<b>100</b>			
Power Supply Quiescent Current	$I_{DD}$	NCx20071	No load		420	625	$\mu\text{A}$
						<b>765</b>	
		NCx20072, NCx20074	Per channel, no load		405	525	
						<b>625</b>	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

11. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

12. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

13. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

## ELECTRICAL CHARACTERISTICS AT $V_S = 5\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis.

**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 14, 15)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Input Offset Voltage	$V_{OS}$	NCx20071		1.3	$\pm 3.5$	mV
					<b><math>\pm 4.5</math></b>	
		NCx20072, NCx20074		1.3	$\pm 3$	
					<b><math>\pm 4</math></b>	
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$		2		$\mu\text{V}/^\circ\text{C}$
Input Bias Current (Note 15)	$I_{IB}$			5	200	pA
					<b>1500</b>	
Input Offset Current (Note 15)	$I_{OS}$	NCx20071, NCx20072		2	75	pA
					<b>500</b>	
		NCx20074		2	75	
					<b>200</b>	
Channel Separation	XTLK	DC	NCx20072	100		dB
			NCx20074	115		
Differential Input Resistance	$R_{ID}$			5		$\text{G}\Omega$
Common Mode Input Resistance	$R_{IN}$			5		$\text{G}\Omega$
Differential Input Capacitance	$C_{ID}$			1.5		pF
Common Mode Input Capacitance	$C_{CM}$			3.5		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

14. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

16. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 5\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis.

**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 14, 15)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
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### INPUT CHARACTERISTICS

Common Mode Rejection Ratio	CMRR	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	102	125		dB
			<b>80</b>			

### OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	$A_{VOL}$		96	120		dB
			<b>86</b>			
Output Current Capability (Note 16)	$I_O$	Op amp sinking current		50		mA
		Op amp sourcing current		60		
Output Voltage High	$V_{OH}$	Voltage output swing from positive rail		0.013	0.20	V
					<b>0.25</b>	
Output Voltage Low	$V_{OL}$	Voltage output swing from negative rail		0.01	0.10	V
					<b>0.15</b>	

### AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	$C_L = 25\text{ pF}$		3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20\text{ pF}$ , $R_L = 2\text{ k}\Omega$		2.7		V/ $\mu\text{s}$
Phase Margin	$\varphi_m$	$C_L = 25\text{ pF}$		50		$^\circ$
Gain Margin	$A_m$	$C_L = 25\text{ pF}$		14		dB
Settling Time	$t_s$	$V_O = 3\text{ Vpp}$ , Gain = 1, $C_L = 20\text{ pF}$	Settling time to 0.1%	1.2		$\mu\text{s}$
			Settling time to 0.01%	5.6		

### NOISE CHARACTERISTICS

Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 2.5\text{ Vpp}$ , $f = 1\text{ kHz}$ , $A_v = 1$		0.009		%
Input Referred Voltage Noise	$e_n$	$f = 1\text{ kHz}$		30		nV/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		20		
Input Referred Current Noise	$i_n$	$f = 1\text{ kHz}$		90		fA/ $\sqrt{\text{Hz}}$

### SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No Load		114	135		dB
				<b>100</b>			
Power Supply Quiescent Current	$I_{DD}$	NCx20071	No load		430	635	$\mu\text{A}$
						<b>775</b>	
		NCx20072, NCx20074	Per channel, no load		410	530	
						<b>630</b>	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

14. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

16. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 10\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 17, 18)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Input Offset Voltage	$V_{OS}$	NCx20071		1.3	$\pm 3.5$	mV
					<b><math>\pm 4.5</math></b>	<b>mV</b>
Input Offset Voltage	$V_{OS}$	NCx20072, NCx20074		1.3	$\pm 3$	mV
					<b><math>\pm 4</math></b>	<b>mV</b>
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$		2		$\mu\text{V}/^\circ\text{C}$
Input Bias Current (Note 18)	$I_{IB}$			5	200	pA
					<b>1500</b>	
Input Offset Current (Note 18)	$I_{OS}$	NCx20071, NCx20072		2	75	pA
					<b>500</b>	
		NCx20074		2	75	
					<b>200</b>	
Channel Separation	XTLK	DC	NCx20072	100		dB
			NCx20074	115		
Differential Input Resistance	$R_{ID}$			5		$\text{G}\Omega$
Common Mode Input Resistance	$R_{IN}$			5		$\text{G}\Omega$
Differential Input Capacitance	$C_{ID}$			1.5		pF
Common Mode Input Capacitance	$C_{CM}$			3.5		pF
Common Mode Rejection Ratio	CMRR	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$		110	130	dB
				<b>87</b>		

## OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	$A_{VOL}$			98	120	dB
				<b>88</b>		
Output Current Capability (Note 19)	$I_O$		Op amp sinking current		50	mA
			Op amp sourcing current		65	
Output Voltage High	$V_{OH}$	Voltage output swing from positive rail		0.023	0.08	V
					<b>0.10</b>	
Output Voltage Low	$V_{OL}$	Voltage output swing from negative rail		0.022	0.3	V
					<b>0.35</b>	

## AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	$C_L = 25\text{ pF}$		3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20\text{ pF}$ , $R_L = 2\text{ k}\Omega$		2.6		$\text{V}/\mu\text{s}$
Phase Margin	$\varphi_m$	$C_L = 25\text{ pF}$		50		$^\circ$
Gain Margin	$A_m$	$C_L = 25\text{ pF}$		14		dB
Settling Time	$t_s$	$V_O = 8.5\text{ Vpp}$ , Gain = 1, $C_L = 20\text{ pF}$	Settling time to 0.1%	3.4		$\mu\text{s}$
			Settling time to 0.01%	6.8		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

17. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

18. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

19. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 10\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 17, 18)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>NOISE CHARACTERISTICS</b>						
Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 7.5\text{ Vpp}$ , $f = 1\text{ kHz}$ , $A_v = 1$		0.004		%
Input Referred Voltage Noise	$e_n$	$f = 1\text{ kHz}$		30		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		20		
Input Referred Current Noise	$i_n$	$f = 1\text{ kHz}$		90		$\text{fA}/\sqrt{\text{Hz}}$

## SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No Load		114	135		dB
				<b>100</b>			
Power Supply Quiescent Current	$I_{DD}$	NCx20071	No load		430	645	$\mu\text{A}$
						<b>785</b>	
		NCx20072, NCx20074	Per channel, no load		416	540	
						<b>640</b>	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

17. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

18. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

19. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

## ELECTRICAL CHARACTERISTICS AT $V_S = 36\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 20, 21)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
<b>INPUT CHARACTERISTICS</b>							
Input Offset Voltage	$V_{OS}$	NCx20071		1.3	$\pm 3.5$	mV	
					<b><math>\pm 4.5</math></b>	<b>mV</b>	
		NCx20072, NCx20074		1.3	$\pm 3$	mV	
					<b><math>\pm 4</math></b>	<b>mV</b>	
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$	2			$\mu\text{V}/^\circ\text{C}$	
Input Bias Current (Note 21)	$I_{IB}$			5	200	pA	
				NCx20071, NCx20072			<b>2000</b>
				NCx20074			<b>1500</b>
Input Offset Current (Note 21)	$I_{OS}$	NCx20071, NCx20072		2	75	pA	
							<b>1000</b>
		NCx20074		2	75		
							<b>200</b>
Channel Separation	XTLK	DC	NCx20072	100		dB	
			NCx20074	115			
Differential Input Resistance	$R_{ID}$			5		$\text{G}\Omega$	
Common Mode Input Resistance	$R_{IN}$			5		$\text{G}\Omega$	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

22. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 36\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 20, 21)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
-----------	--------	------------	-----	-----	-----	------

### INPUT CHARACTERISTICS

Differential Input Capacitance	$C_{ID}$			1.5		pF
Common Mode Input Capacitance	$C_{CM}$			3.5		pF
Common Mode Rejection Ratio	CMRR	NCx20071	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	118	135	dB
				<b>95</b>		
		NCx20072	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	120	145	
				<b>95</b>		
		NCx20074	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	120	145	
				<b>85</b>		

### OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	$A_{VOL}$		98	120	dB	
			<b>88</b>			
Output Current Capability (Note 22)	$I_O$	Op amp sinking current		50	mA	
		Op amp sourcing current		65		
Output Voltage High	$V_{OH}$	Voltage output swing from positive rail	NCx20071	0.074	0.15	V
				<b>0.22</b>		
			NCx20072	0.074	0.10	
				<b>0.15</b>		
			NCx20074	0.074	0.10	
				<b>0.12</b>		
Output Voltage Low	$V_{OL}$	Voltage output swing from negative rail		0.065	0.3	V
					<b>0.35</b>	

### AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	$C_L = 25\text{ pF}$		3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20\text{ pF}$ , $R_L = 2\text{ k}\Omega$		2.4		$\text{V}/\mu\text{s}$
Phase Margin	$\varphi_m$	$C_L = 25\text{ pF}$		50		$^\circ$
Gain Margin	$A_m$	$C_L = 25\text{ pF}$		14		dB
Settling Time	$t_s$	$V_O = 10\text{ Vpp}$ , Gain = 1, $C_L = 20\text{ pF}$	Settling time to 0.1%	3.2		$\mu\text{s}$
			Settling time to 0.01%	7		

### NOISE CHARACTERISTICS

Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 28.5\text{ Vpp}$ , $f = 1\text{ kHz}$ , $A_v = 1$		0.001		%
Input Referred Voltage Noise	$e_n$	$f = 1\text{ kHz}$		30		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		20		
Input Referred Current Noise	$i_n$	$f = 1\text{ kHz}$		90		$\text{fA}/\sqrt{\text{Hz}}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

22. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# NCS20071, NCV20071, NCS20072, NCV20072, NCS20074, NCV20074

## ELECTRICAL CHARACTERISTICS AT $V_S = 36\text{ V}$

$T_A = 25^\circ\text{C}$ ;  $R_L \geq 10\text{ k}\Omega$ ;  $V_{CM} = V_{OUT} = \text{mid-supply}$  unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ . (Notes 20, 21)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
-----------	--------	------------	-----	-----	-----	------

### SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No Load		114	135		dB
				<b>100</b>			
Power Supply Quiescent Current	I <sub>DD</sub>	NCx20071	No load		480	700	μA
		NCx20072	Per channel, no load			<b>840</b>	
					465	570	
		NCx20074	Per channel, no load		465	600	
						<b>700</b>	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

22. Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

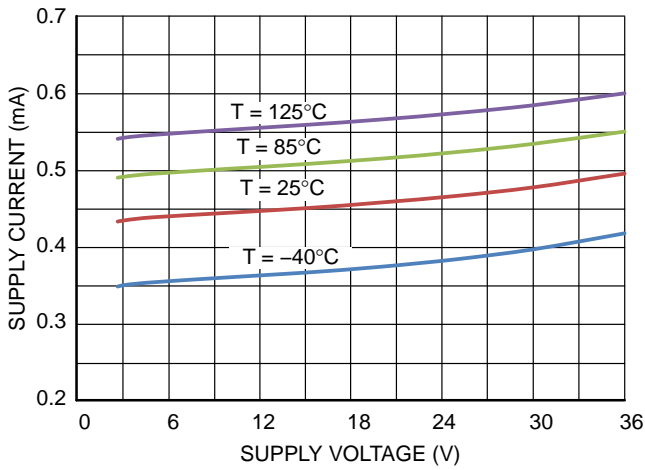


Figure 2. Quiescent Current Per Channel vs. Supply Voltage

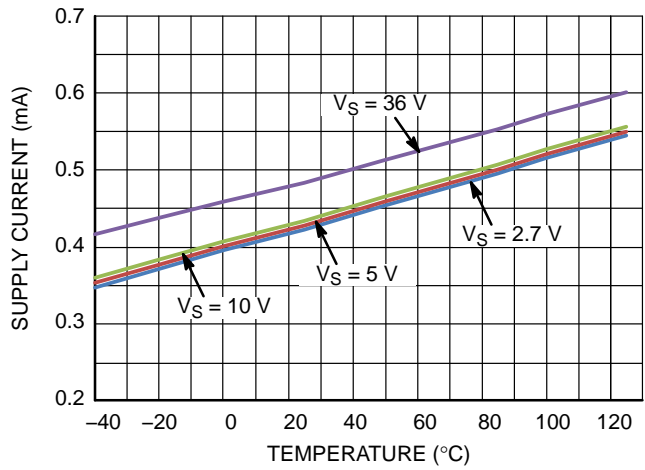


Figure 3. Quiescent Current vs. Temperature

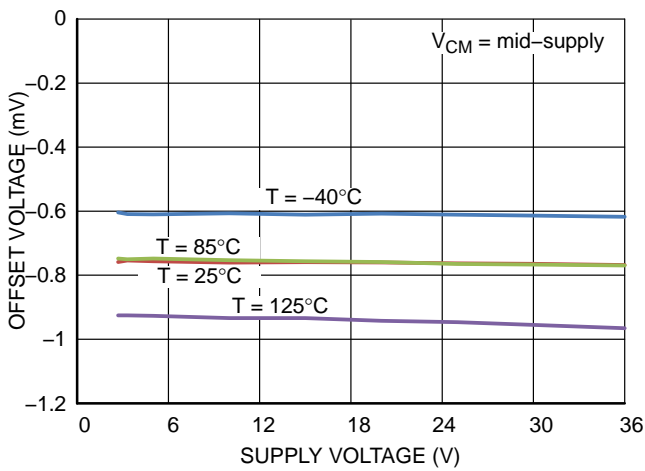


Figure 4. Offset Voltage vs. Supply Voltage

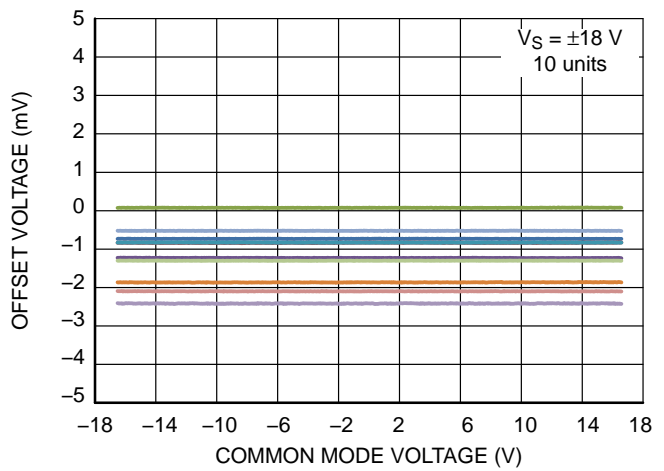


Figure 5. Input Offset Voltage vs. Common Mode Voltage

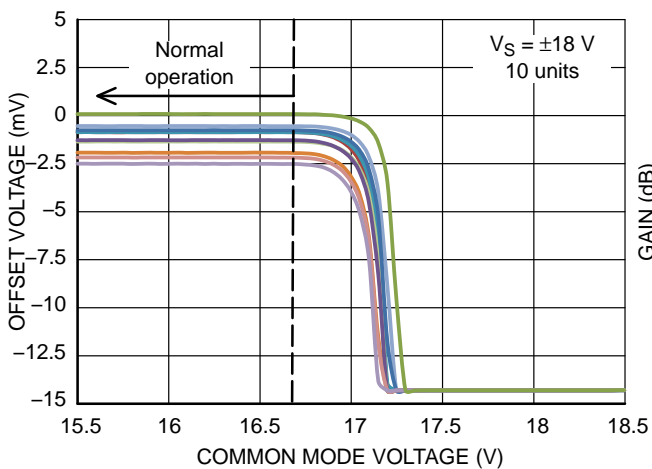


Figure 6. Input Offset Voltage vs. Common Mode Voltage

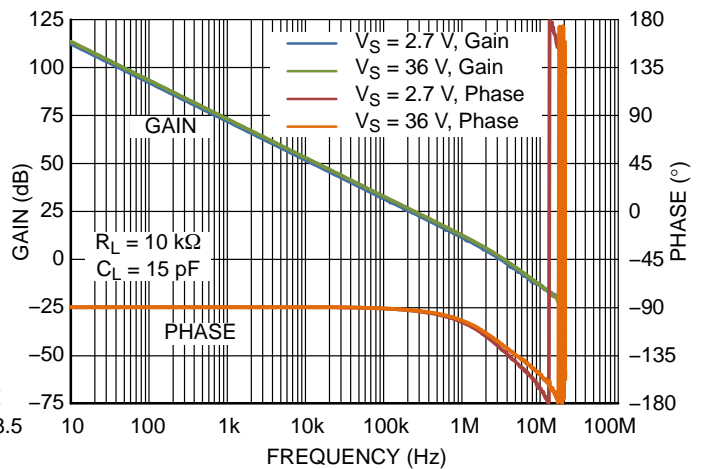


Figure 7. Gain and Phase vs. Frequency

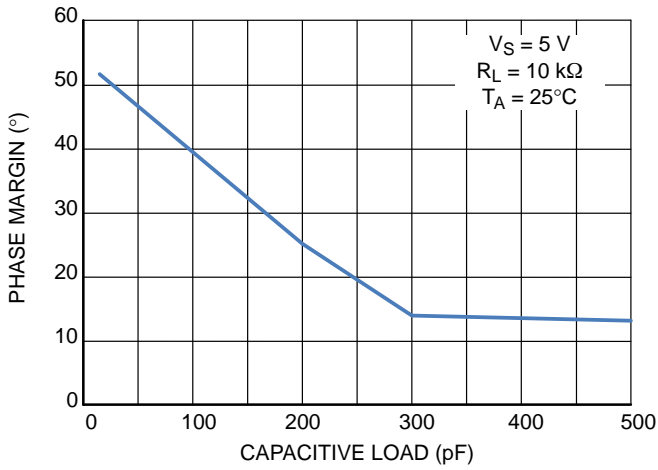


Figure 8. Phase Margin vs. Capacitive Load

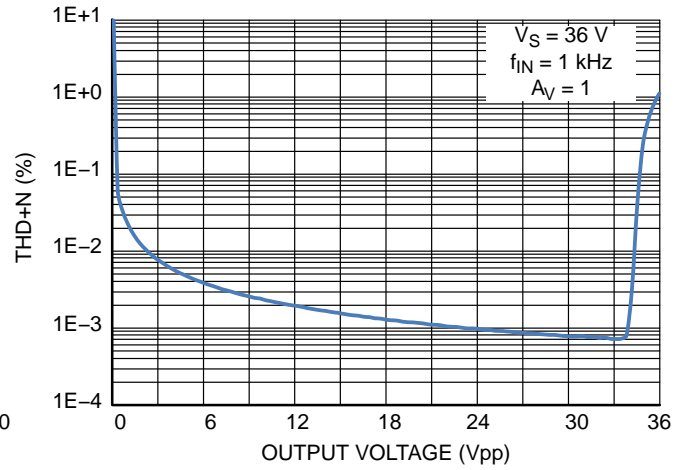


Figure 9. THD+N vs. Output Voltage

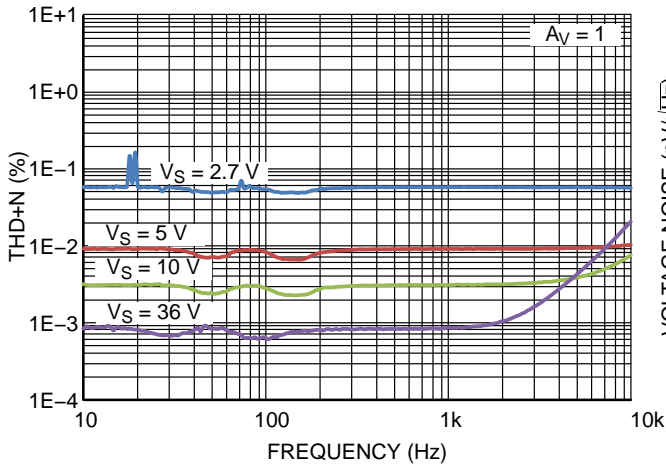


Figure 10. THD+N vs. Frequency

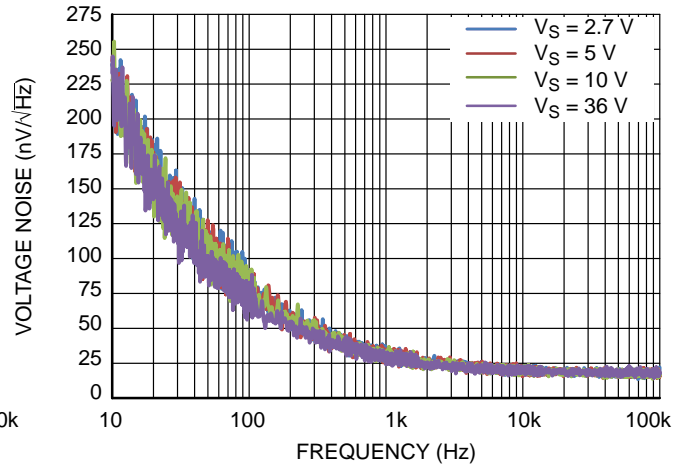


Figure 11. Input Voltage Noise vs. Frequency

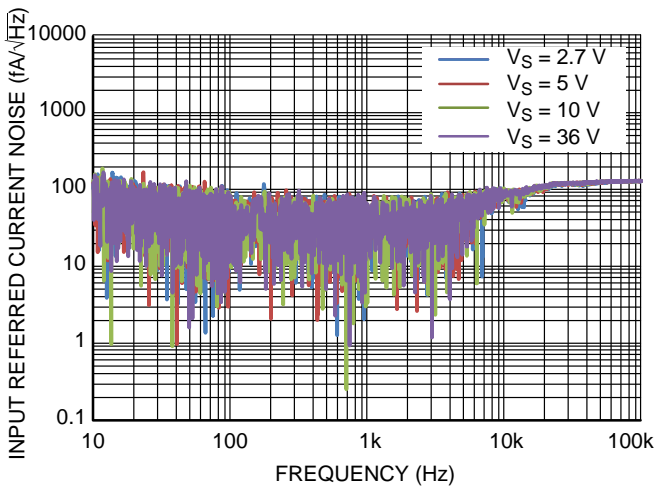


Figure 12. Input Current Noise vs. Frequency

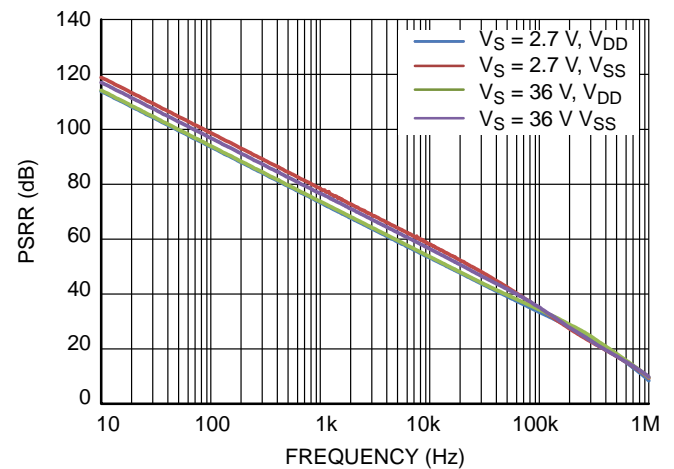


Figure 13. PSRR vs. Frequency

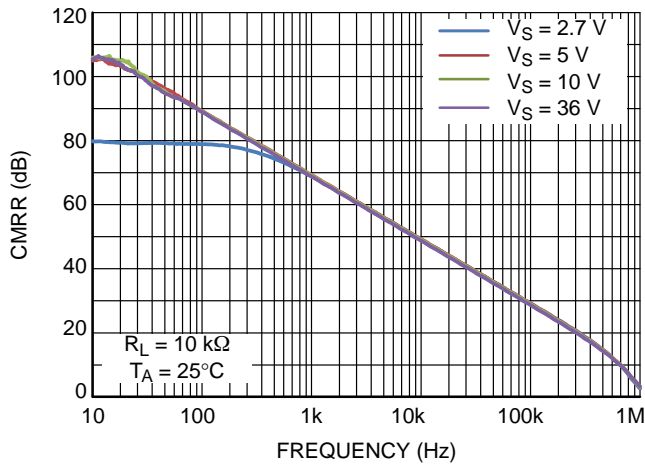


Figure 14. CMRR vs. Frequency

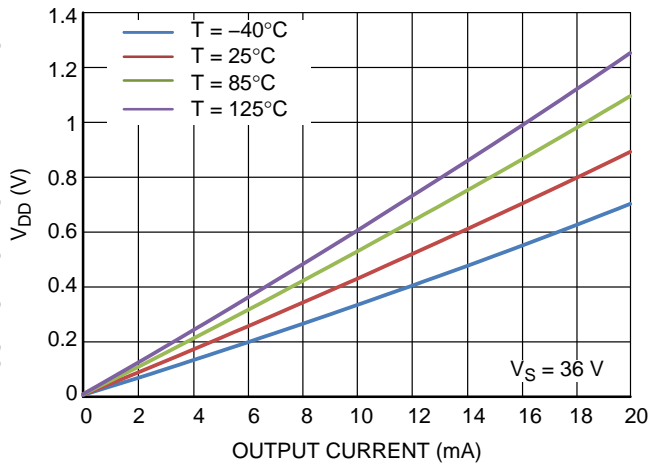


Figure 15. High Level Output vs. Output Current

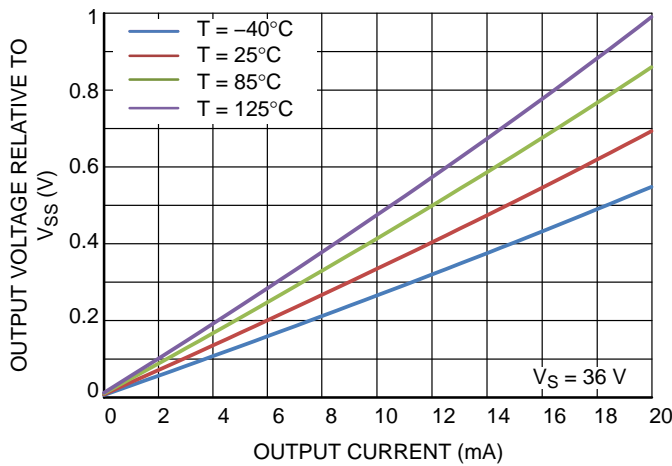


Figure 16. Low Level Output vs. Output Current

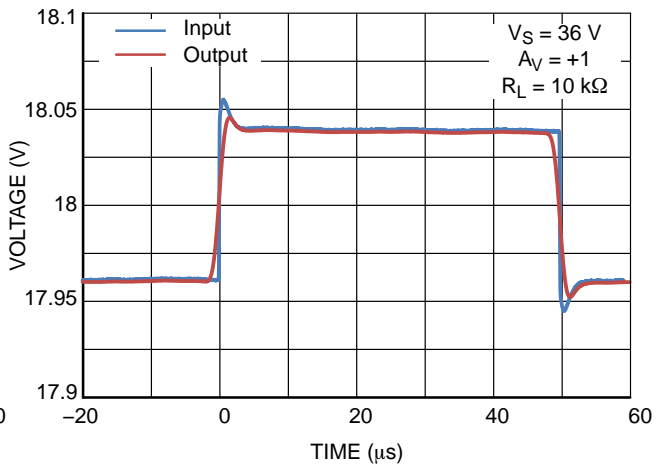


Figure 17. Non-inverting Small Signal Transient Response

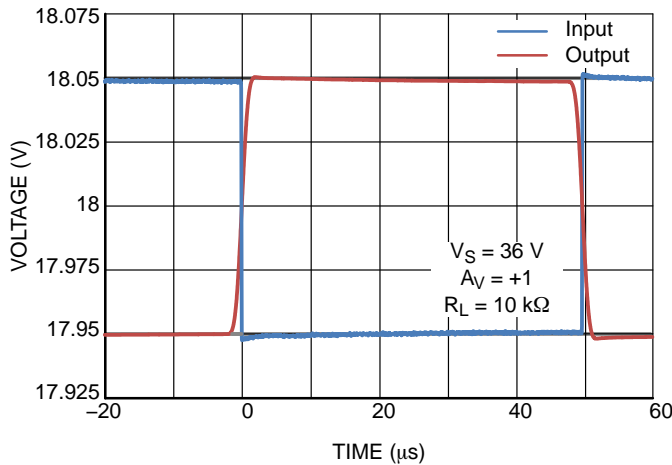


Figure 18. Inverting Small Signal Transient Response

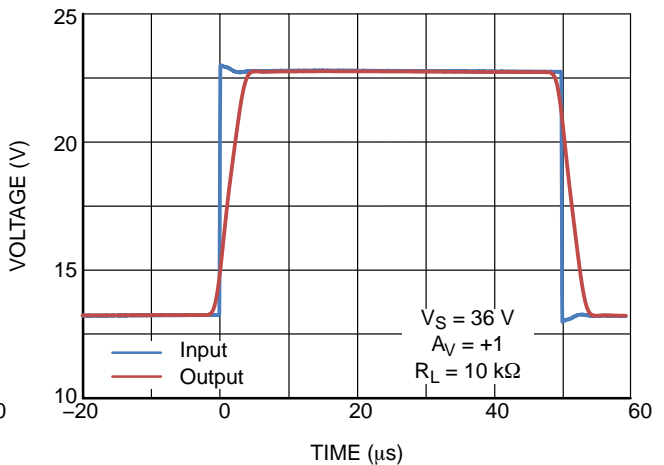


Figure 19. Non-inverting Large Signal Transient Response

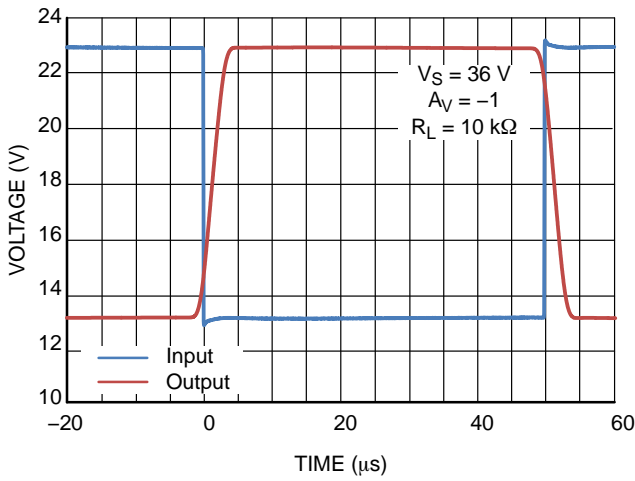


Figure 20. Inverting Large Signal Transient Response

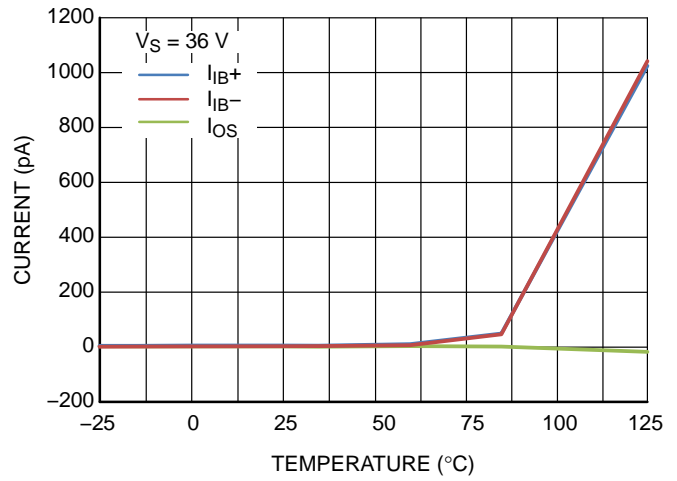


Figure 21. Input Bias and Offset Current vs. Temperature

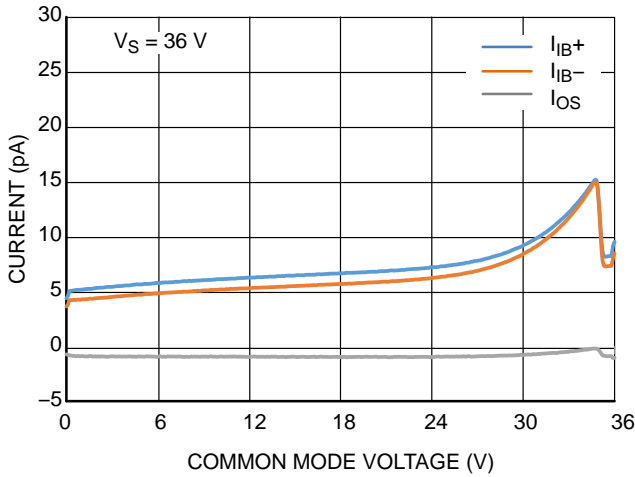


Figure 22. Input Bias Current vs. Common Mode Voltage

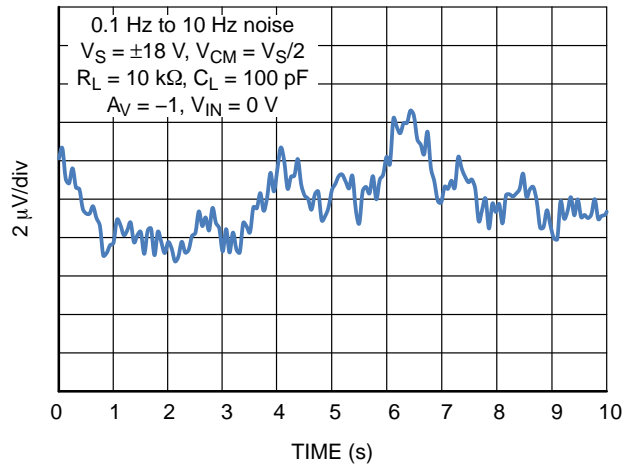


Figure 23. 0.1 Hz to 10 Hz Noise

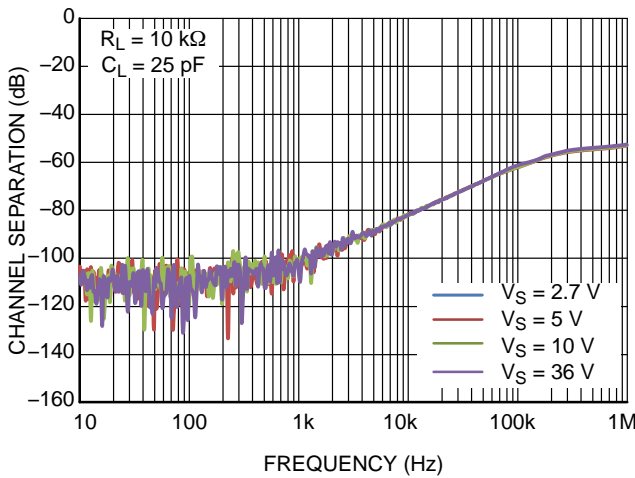


Figure 24. Channel Separation vs. Frequency

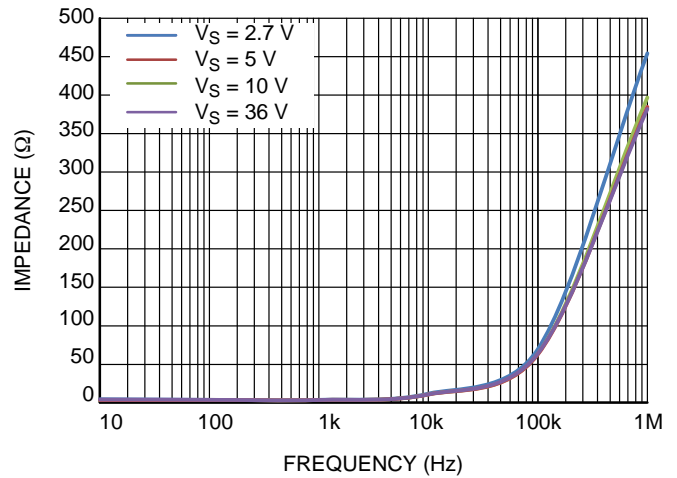


Figure 25. Open Loop Output Impedance

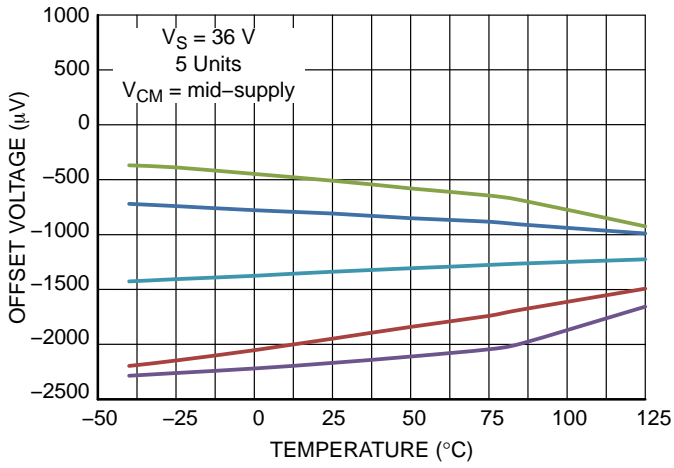


Figure 26. Offset Voltage vs. Temperature

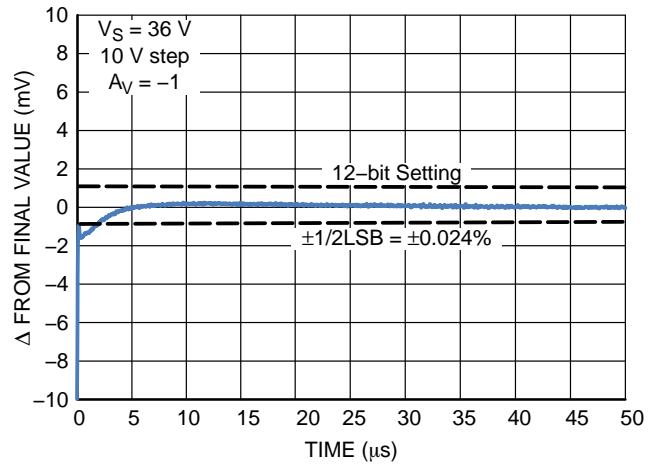


Figure 27. Large Signal Settling Time

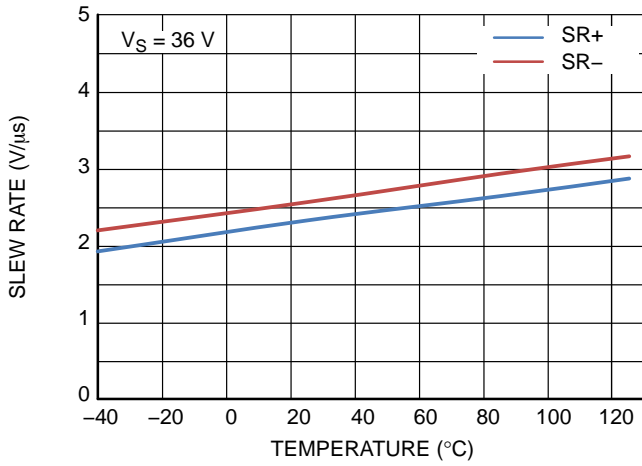


Figure 28. Slew Rate vs. Temperature

APPLICATIONS INFORMATION

**Input Circuit**

The NCS2007x input stage has a PMOS input pair and ESD protection diodes. The input pair is internally connected by back-to-back Zener diodes with a reverse voltage of 5.5 V. To protect the internal circuitry, the input current must be limited to 10 mA. When operating the

NCS2007x at differential voltages greater than  $V_{ID} = 26$  V, series resistors can be added externally to limit the input current flowing between the input pins. Adding 500  $\Omega$  resistors in series with the input prevents the current from exceeding 10 mA over the entire operating range up to 36 V.

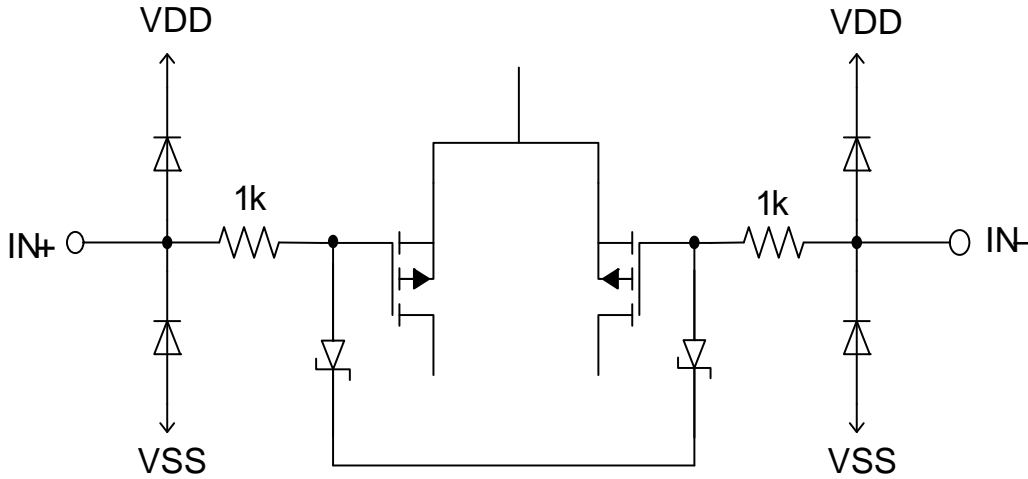


Figure 29. Differential Input Pair

**Output**

The NCS2007x has a class AB output stage with rail-to-rail output swing.

High output currents can cause the junction temperature to exceed the 150°C absolute maximum rating. In the case of a short circuit where the output is connected to either supply rail, the amount of current the op amp can source and sink is described by the output current capability parameter

listed in the Electrical Characteristics. The junction temperature at a given power dissipation, P, can be calculated using the following formula:

$$T_J = T_A + P \times \theta_{JA}$$

The thermal resistance between junction and ambient,  $\theta_{JA}$ , is provided in the Thermal Information section of this datasheet.

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

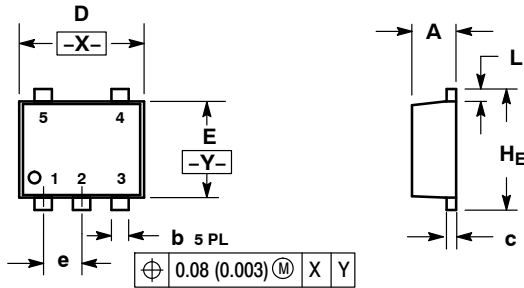
ON Semiconductor®



SCALE 4:1

### SOT-553, 5 LEAD CASE 463B ISSUE C

DATE 20 MAR 2013

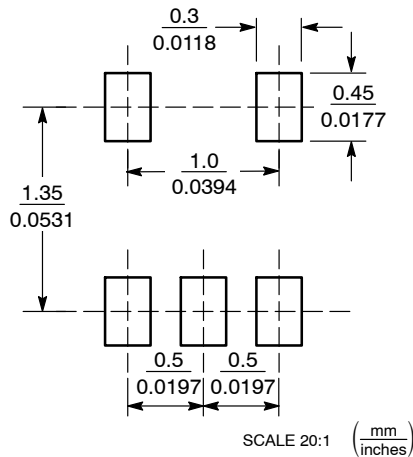


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
c	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
e	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H <sub>E</sub>	1.55	1.60	1.65	0.061	0.063	0.065

### RECOMMENDED SOLDERING FOOTPRINT\*



### GENERIC MARKING DIAGRAM\*



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**STYLE 1:**

- PIN 1. BASE
- 2. EMITTER
- 3. BASE
- 4. COLLECTOR
- 5. COLLECTOR

**STYLE 2:**

- PIN 1. CATHODE
- 2. COMMON ANODE
- 3. CATHODE 2
- 4. CATHODE 3
- 5. CATHODE 4

**STYLE 3:**

- PIN 1. ANODE 1
- 2. N/C
- 3. ANODE 2
- 4. CATHODE 2
- 5. CATHODE 1

**STYLE 4:**

- PIN 1. SOURCE 1
- 2. DRAIN 1/2
- 3. SOURCE 1
- 4. GATE 1
- 5. GATE 2

**STYLE 5:**

- PIN 1. ANODE
- 2. EMITTER
- 3. BASE
- 4. COLLECTOR
- 5. CATHODE

**STYLE 6:**

- PIN 1. EMITTER 2
- 2. BASE 2
- 3. EMITTER 1
- 4. COLLECTOR 1
- 5. COLLECTOR 2/BASE 1

**STYLE 7:**

- PIN 1. BASE
- 2. EMITTER
- 3. BASE
- 4. COLLECTOR
- 5. COLLECTOR

**STYLE 8:**

- PIN 1. CATHODE
- 2. COLLECTOR
- 3. N/C
- 4. BASE
- 5. EMITTER

**STYLE 9:**

- PIN 1. ANODE
- 2. CATHODE
- 3. ANODE
- 4. ANODE
- 5. ANODE

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<b>STATUS:</b>	<b>ON SEMICONDUCTOR STANDARD</b>	
<b>NEW STANDARD:</b>		
<b>DESCRIPTION:</b>	<b>SOT-553, 5 LEAD</b>	<b>PAGE 1 OF 2</b>



# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

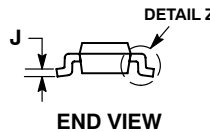
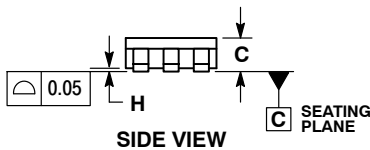
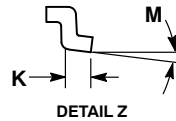
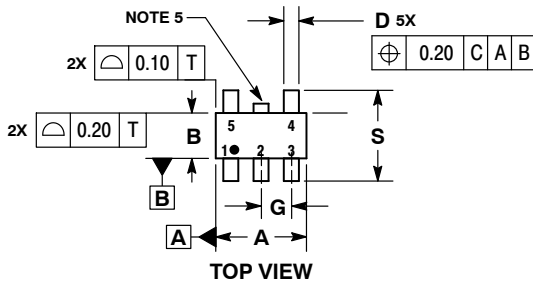
ON Semiconductor®



SCALE 2:1

## TSOP-5 CASE 483 ISSUE N

DATE 12 AUG 2020

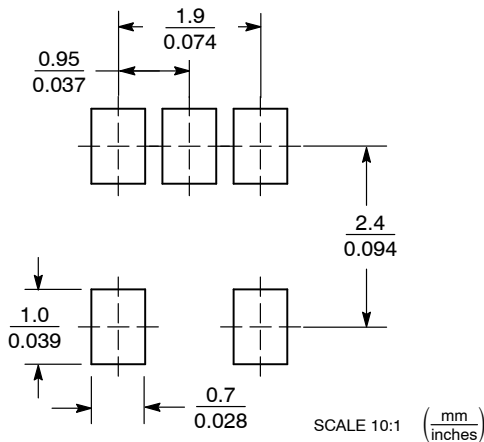


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

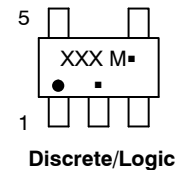
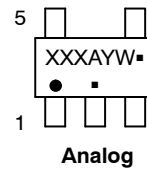
DIM	MILLIMETERS	
	MIN	MAX
A	2.85	3.15
B	1.35	1.65
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM\*



- XXX = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 W = Work Week  
 ■ = Pb-Free Package
- XXX = Specific Device Code  
 M = Date Code  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

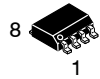
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present.

DOCUMENT NUMBER:	98ARB18753C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSOP-5	PAGE 1 OF 1

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

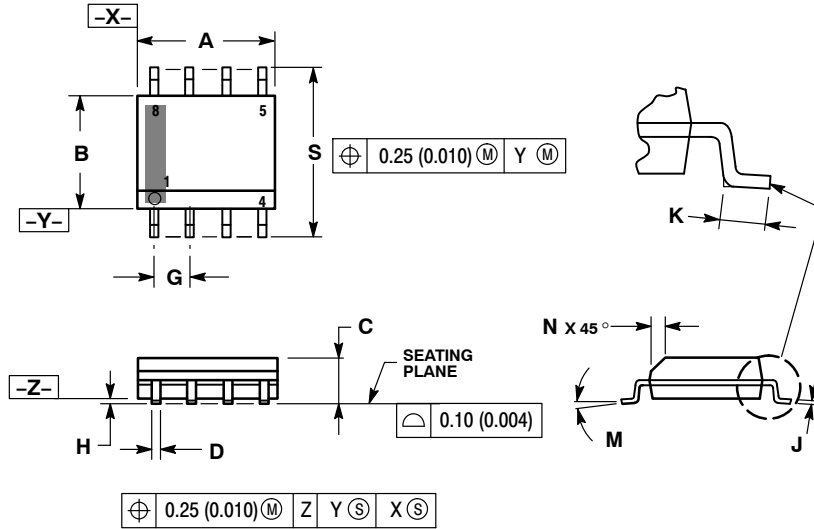
ON Semiconductor®



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

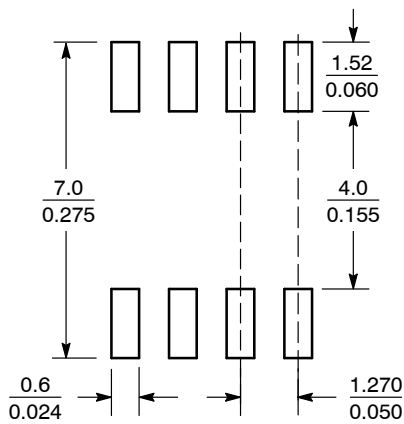
DATE 16 FEB 2011



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
  6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

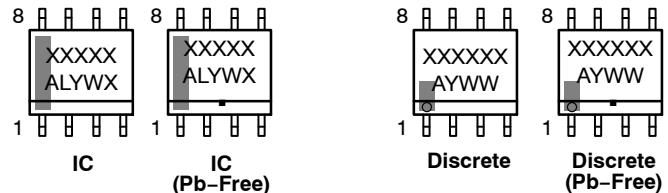
### SOLDERING FOOTPRINT\*



SCALE 6:1 (mm/inches)

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

### STYLES ON PAGE 2

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DESCRIPTION:	SOIC-8 NB	PAGE 1 OF 2


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**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

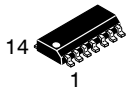
DATE 16 FEB 2011

- |  |   |   |   |
|--|---|---|---|
| <p><b>STYLE 1:</b><br/>         PIN 1. EMITTER<br/>         2. COLLECTOR<br/>         3. COLLECTOR<br/>         4. EMITTER<br/>         5. EMITTER<br/>         6. BASE<br/>         7. BASE<br/>         8. EMITTER</p>   | <p><b>STYLE 2:</b><br/>         PIN 1. COLLECTOR, DIE, #1<br/>         2. COLLECTOR, #1<br/>         3. COLLECTOR, #2<br/>         4. COLLECTOR, #2<br/>         5. BASE, #2<br/>         6. EMITTER, #2<br/>         7. BASE, #1<br/>         8. EMITTER, #1</p>               | <p><b>STYLE 3:</b><br/>         PIN 1. DRAIN, DIE #1<br/>         2. DRAIN, #1<br/>         3. DRAIN, #2<br/>         4. DRAIN, #2<br/>         5. GATE, #2<br/>         6. SOURCE, #2<br/>         7. GATE, #1<br/>         8. SOURCE, #1</p>                            | <p><b>STYLE 4:</b><br/>         PIN 1. ANODE<br/>         2. ANODE<br/>         3. ANODE<br/>         4. ANODE<br/>         5. ANODE<br/>         6. ANODE<br/>         7. ANODE<br/>         8. COMMON CATHODE</p>   |
| <p><b>STYLE 5:</b><br/>         PIN 1. DRAIN<br/>         2. DRAIN<br/>         3. DRAIN<br/>         4. DRAIN<br/>         5. GATE<br/>         6. GATE<br/>         7. SOURCE<br/>         8. SOURCE</p>   | <p><b>STYLE 6:</b><br/>         PIN 1. SOURCE<br/>         2. DRAIN<br/>         3. DRAIN<br/>         4. SOURCE<br/>         5. SOURCE<br/>         6. GATE<br/>         7. GATE<br/>         8. SOURCE</p>  | <p><b>STYLE 7:</b><br/>         PIN 1. INPUT<br/>         2. EXTERNAL BYPASS<br/>         3. THIRD STAGE SOURCE<br/>         4. GROUND<br/>         5. DRAIN<br/>         6. GATE 3<br/>         7. SECOND STAGE Vd<br/>         8. FIRST STAGE Vd</p>                    | <p><b>STYLE 8:</b><br/>         PIN 1. COLLECTOR, DIE #1<br/>         2. BASE, #1<br/>         3. BASE, #2<br/>         4. COLLECTOR, #2<br/>         5. COLLECTOR, #2<br/>         6. EMITTER, #2<br/>         7. EMITTER, #1<br/>         8. COLLECTOR, #1</p>                              |
| <p><b>STYLE 9:</b><br/>         PIN 1. EMITTER, COMMON<br/>         2. COLLECTOR, DIE #1<br/>         3. COLLECTOR, DIE #2<br/>         4. EMITTER, COMMON<br/>         5. EMITTER, COMMON<br/>         6. BASE, DIE #2<br/>         7. BASE, DIE #1<br/>         8. EMITTER, COMMON</p> | <p><b>STYLE 10:</b><br/>         PIN 1. GROUND<br/>         2. BIAS 1<br/>         3. OUTPUT<br/>         4. GROUND<br/>         5. GROUND<br/>         6. BIAS 2<br/>         7. INPUT<br/>         8. GROUND</p>  | <p><b>STYLE 11:</b><br/>         PIN 1. SOURCE 1<br/>         2. GATE 1<br/>         3. SOURCE 2<br/>         4. GATE 2<br/>         5. DRAIN 2<br/>         6. DRAIN 2<br/>         7. DRAIN 1<br/>         8. DRAIN 1</p>   | <p><b>STYLE 12:</b><br/>         PIN 1. SOURCE<br/>         2. SOURCE<br/>         3. SOURCE<br/>         4. GATE<br/>         5. DRAIN<br/>         6. DRAIN<br/>         7. DRAIN<br/>         8. DRAIN</p>   |
| <p><b>STYLE 13:</b><br/>         PIN 1. N.C.<br/>         2. SOURCE<br/>         3. SOURCE<br/>         4. GATE<br/>         5. DRAIN<br/>         6. DRAIN<br/>         7. DRAIN<br/>         8. DRAIN</p>  | <p><b>STYLE 14:</b><br/>         PIN 1. N-SOURCE<br/>         2. N-GATE<br/>         3. P-SOURCE<br/>         4. P-GATE<br/>         5. P-DRAIN<br/>         6. P-DRAIN<br/>         7. N-DRAIN<br/>         8. N-DRAIN</p>   | <p><b>STYLE 15:</b><br/>         PIN 1. ANODE 1<br/>         2. ANODE 1<br/>         3. ANODE 1<br/>         4. ANODE 1<br/>         5. CATHODE, COMMON<br/>         6. CATHODE, COMMON<br/>         7. CATHODE, COMMON<br/>         8. CATHODE, COMMON</p>               | <p><b>STYLE 16:</b><br/>         PIN 1. EMITTER, DIE #1<br/>         2. BASE, DIE #1<br/>         3. EMITTER, DIE #2<br/>         4. BASE, DIE #2<br/>         5. COLLECTOR, DIE #2<br/>         6. COLLECTOR, DIE #2<br/>         7. COLLECTOR, DIE #1<br/>         8. COLLECTOR, DIE #1</p> |
| <p><b>STYLE 17:</b><br/>         PIN 1. VCC<br/>         2. V2OUT<br/>         3. V1OUT<br/>         4. TXE<br/>         5. RXE<br/>         6. VEE<br/>         7. GND<br/>         8. ACC</p>  | <p><b>STYLE 18:</b><br/>         PIN 1. ANODE<br/>         2. ANODE<br/>         3. SOURCE<br/>         4. GATE<br/>         5. DRAIN<br/>         6. DRAIN<br/>         7. CATHODE<br/>         8. CATHODE</p>   | <p><b>STYLE 19:</b><br/>         PIN 1. SOURCE 1<br/>         2. GATE 1<br/>         3. SOURCE 2<br/>         4. GATE 2<br/>         5. DRAIN 2<br/>         6. MIRROR 2<br/>         7. DRAIN 1<br/>         8. MIRROR 1</p>   | <p><b>STYLE 20:</b><br/>         PIN 1. SOURCE (N)<br/>         2. GATE (N)<br/>         3. SOURCE (P)<br/>         4. GATE (P)<br/>         5. DRAIN<br/>         6. DRAIN<br/>         7. DRAIN<br/>         8. DRAIN</p>   |
| <p><b>STYLE 21:</b><br/>         PIN 1. CATHODE 1<br/>         2. CATHODE 2<br/>         3. CATHODE 3<br/>         4. CATHODE 4<br/>         5. CATHODE 5<br/>         6. COMMON ANODE<br/>         7. COMMON ANODE<br/>         8. CATHODE 6</p>  | <p><b>STYLE 22:</b><br/>         PIN 1. I/O LINE 1<br/>         2. COMMON CATHODE/VCC<br/>         3. COMMON CATHODE/VCC<br/>         4. I/O LINE 3<br/>         5. COMMON ANODE/GND<br/>         6. I/O LINE 4<br/>         7. I/O LINE 5<br/>         8. COMMON ANODE/GND</p> | <p><b>STYLE 23:</b><br/>         PIN 1. LINE 1 IN<br/>         2. COMMON ANODE/GND<br/>         3. COMMON ANODE/GND<br/>         4. LINE 2 IN<br/>         5. LINE 2 OUT<br/>         6. COMMON ANODE/GND<br/>         7. COMMON ANODE/GND<br/>         8. LINE 1 OUT</p> | <p><b>STYLE 24:</b><br/>         PIN 1. BASE<br/>         2. EMITTER<br/>         3. COLLECTOR/ANODE<br/>         4. COLLECTOR/ANODE<br/>         5. CATHODE<br/>         6. CATHODE<br/>         7. COLLECTOR/ANODE<br/>         8. COLLECTOR/ANODE</p>                                      |
| <p><b>STYLE 25:</b><br/>         PIN 1. VIN<br/>         2. N/C<br/>         3. REXT<br/>         4. GND<br/>         5. IOUT<br/>         6. IOUT<br/>         7. IOUT<br/>         8. IOUT</p>   | <p><b>STYLE 26:</b><br/>         PIN 1. GND<br/>         2. dv/dt<br/>         3. ENABLE<br/>         4. ILIMIT<br/>         5. SOURCE<br/>         6. SOURCE<br/>         7. SOURCE<br/>         8. VCC</p>  | <p><b>STYLE 27:</b><br/>         PIN 1. ILIMIT<br/>         2. OVLO<br/>         3. UVLO<br/>         4. INPUT+<br/>         5. SOURCE<br/>         6. SOURCE<br/>         7. SOURCE<br/>         8. DRAIN</p>  | <p><b>STYLE 28:</b><br/>         PIN 1. SW_TO_GND<br/>         2. DASIC OFF<br/>         3. DASIC_SW_DET<br/>         4. GND<br/>         5. V_MON<br/>         6. VBULK<br/>         7. VBULK<br/>         8. VIN</p>  |
| <p><b>STYLE 29:</b><br/>         PIN 1. BASE, DIE #1<br/>         2. EMITTER, #1<br/>         3. BASE, #2<br/>         4. EMITTER, #2<br/>         5. COLLECTOR, #2<br/>         6. COLLECTOR, #2<br/>         7. COLLECTOR, #1<br/>         8. COLLECTOR, #1</p>                        | <p><b>STYLE 30:</b><br/>         PIN 1. DRAIN 1<br/>         2. DRAIN 1<br/>         3. GATE 2<br/>         4. SOURCE 2<br/>         5. SOURCE 1/DRAIN 2<br/>         6. SOURCE 1/DRAIN 2<br/>         7. SOURCE 1/DRAIN 2<br/>         8. GATE 1</p>                           |   |   |

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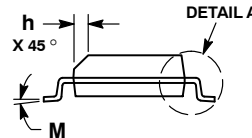
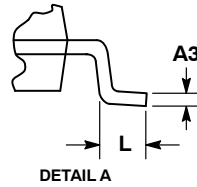
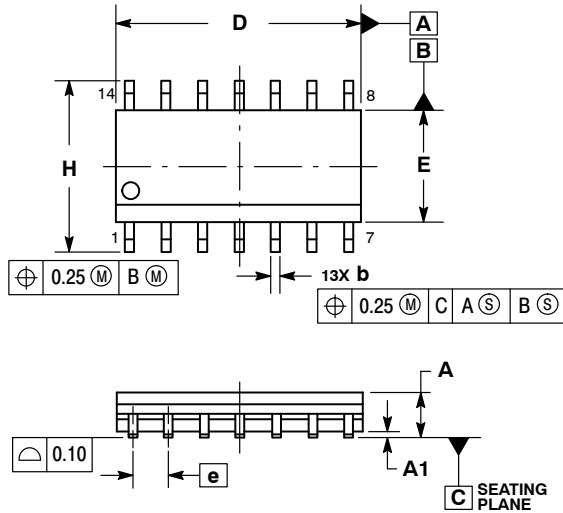
# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 1:1

SOIC-14 NB  
CASE 751A-03  
ISSUE L

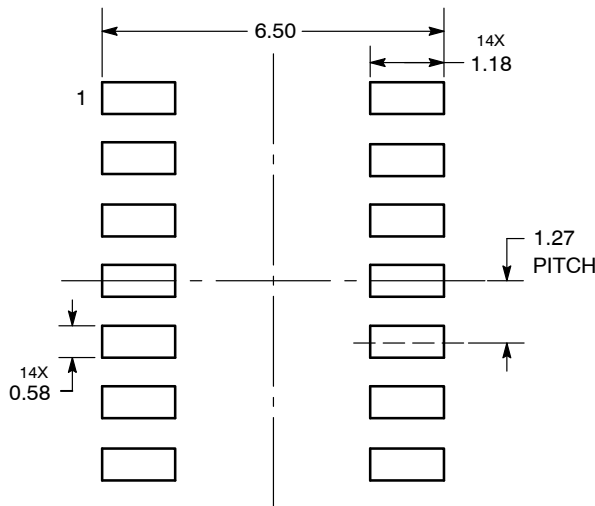
DATE 03 FEB 2016



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
  5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

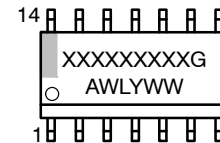
### SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM\*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-14 NB	PAGE 1 OF 2

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**SOIC-14**  
**CASE 751A-03**  
**ISSUE L**

DATE 03 FEB 2016

STYLE 1:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. NO CONNECTION  
 5. ANODE/CATHODE  
 6. NO CONNECTION  
 7. ANODE/CATHODE  
 8. ANODE/CATHODE  
 9. ANODE/CATHODE  
 10. NO CONNECTION  
 11. ANODE/CATHODE  
 12. ANODE/CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 2:  
 CANCELLED

STYLE 3:  
 PIN 1. NO CONNECTION  
 2. ANODE  
 3. ANODE  
 4. NO CONNECTION  
 5. ANODE  
 6. NO CONNECTION  
 7. ANODE  
 8. ANODE  
 9. ANODE  
 10. NO CONNECTION  
 11. ANODE  
 12. ANODE  
 13. NO CONNECTION  
 14. COMMON CATHODE

STYLE 4:  
 PIN 1. NO CONNECTION  
 2. CATHODE  
 3. CATHODE  
 4. NO CONNECTION  
 5. CATHODE  
 6. NO CONNECTION  
 7. CATHODE  
 8. CATHODE  
 9. CATHODE  
 10. NO CONNECTION  
 11. CATHODE  
 12. CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 5:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. ANODE/CATHODE  
 5. ANODE/CATHODE  
 6. NO CONNECTION  
 7. COMMON ANODE  
 8. COMMON CATHODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. ANODE/CATHODE  
 12. ANODE/CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 6:  
 PIN 1. CATHODE  
 2. CATHODE  
 3. CATHODE  
 4. CATHODE  
 5. CATHODE  
 6. CATHODE  
 7. CATHODE  
 8. ANODE  
 9. ANODE  
 10. ANODE  
 11. ANODE  
 12. ANODE  
 13. ANODE  
 14. ANODE

STYLE 7:  
 PIN 1. ANODE/CATHODE  
 2. COMMON ANODE  
 3. COMMON CATHODE  
 4. ANODE/CATHODE  
 5. ANODE/CATHODE  
 6. ANODE/CATHODE  
 7. ANODE/CATHODE  
 8. ANODE/CATHODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. COMMON CATHODE  
 12. COMMON ANODE  
 13. ANODE/CATHODE  
 14. ANODE/CATHODE

STYLE 8:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. NO CONNECTION  
 5. ANODE/CATHODE  
 6. ANODE/CATHODE  
 7. COMMON ANODE  
 8. COMMON ANODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. NO CONNECTION  
 12. ANODE/CATHODE  
 13. ANODE/CATHODE  
 14. COMMON CATHODE

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<b>DESCRIPTION:</b>	<b>SOIC-14 NB</b>	<b>PAGE 2 OF 2</b>

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

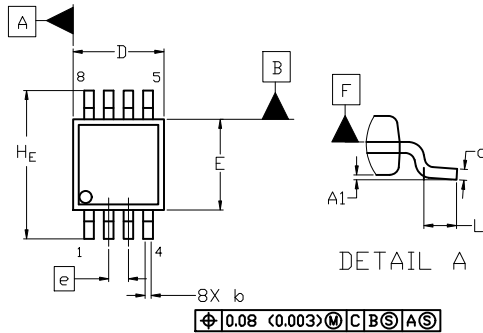
ON Semiconductor®



SCALE 2:1

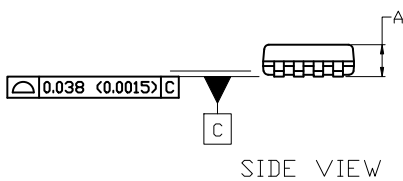
## Micro8 CASE 846A-02 ISSUE K

DATE 16 JUL 2020

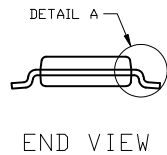


TOP VIEW

NOTE 3



SIDE VIEW

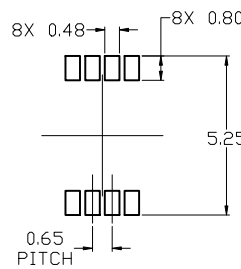


END VIEW

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION *b* DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS *D* AND *E* DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION *E* DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS *D* AND *E* ARE DETERMINED AT DATUM *F*.
5. DATUMS *A* AND *B* ARE TO BE DETERMINED AT DATUM *F*.
6. *A1* IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

$\phi 0.08$  (0.003) M C B S A S

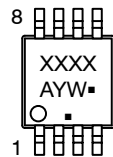


RECOMMENDED  
MOUNTING FOOTPRINT

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	---	---	1.10
A1	0.05	0.08	0.15
<i>b</i>	0.25	0.33	0.40
<i>c</i>	0.13	0.18	0.23
<i>D</i>	2.90	3.00	3.10
<i>E</i>	2.90	3.00	3.10
<i>e</i>	0.65 BSC		
<i>H<sub>E</sub></i>	4.75	4.90	5.05
<i>L</i>	0.40	0.55	0.70

For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

### GENERIC MARKING DIAGRAM\*



- XXXX = Specific Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

**STYLE 1:**

1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

**STYLE 2:**

1. SOURCE 1
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN 1
8. DRAIN 1

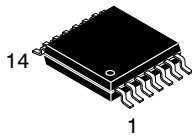
**STYLE 3:**

1. N-SOURCE
2. N-GATE
3. P-SOURCE
4. P-GATE
5. P-DRAIN
6. P-DRAIN
7. N-DRAIN
8. N-DRAIN

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<b>DESCRIPTION:</b>	<b>MICRO8</b>	<b>PAGE 1 OF 1</b>

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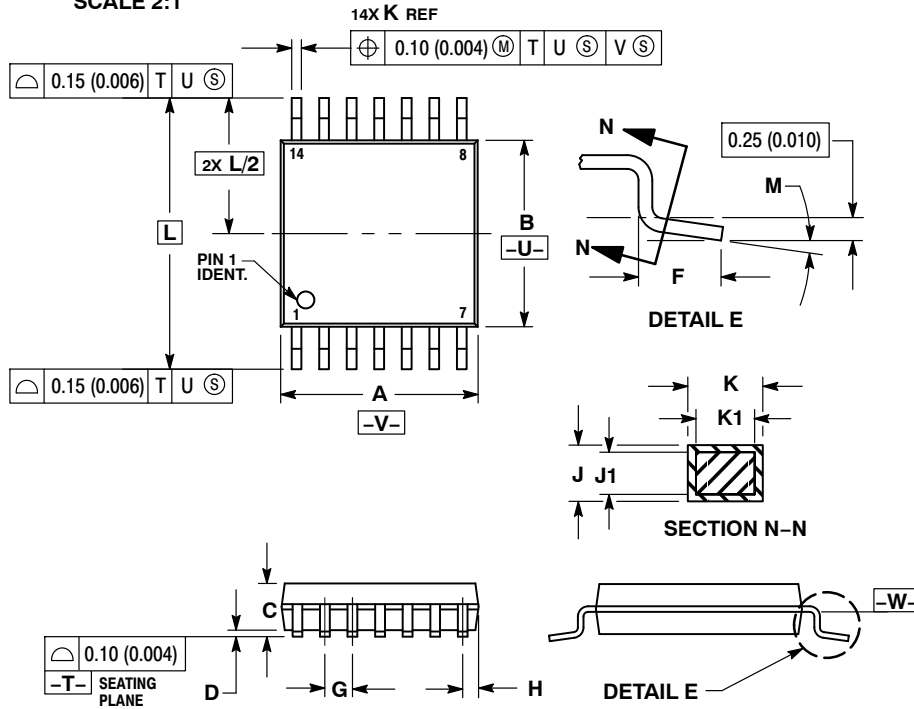
# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



**TSSOP-14 WB**  
CASE 948G  
ISSUE C

DATE 17 FEB 2016

SCALE 2:1

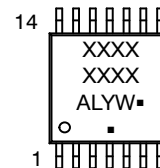


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

**GENERIC MARKING DIAGRAM\***

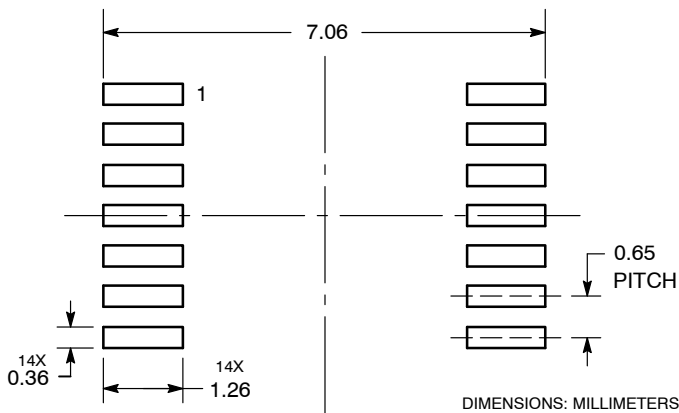


- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

**SOLDERING FOOTPRINT**

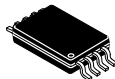


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<b>DESCRIPTION:</b>	<b>TSSOP-14 WB</b>	<b>PAGE 1 OF 1</b>

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

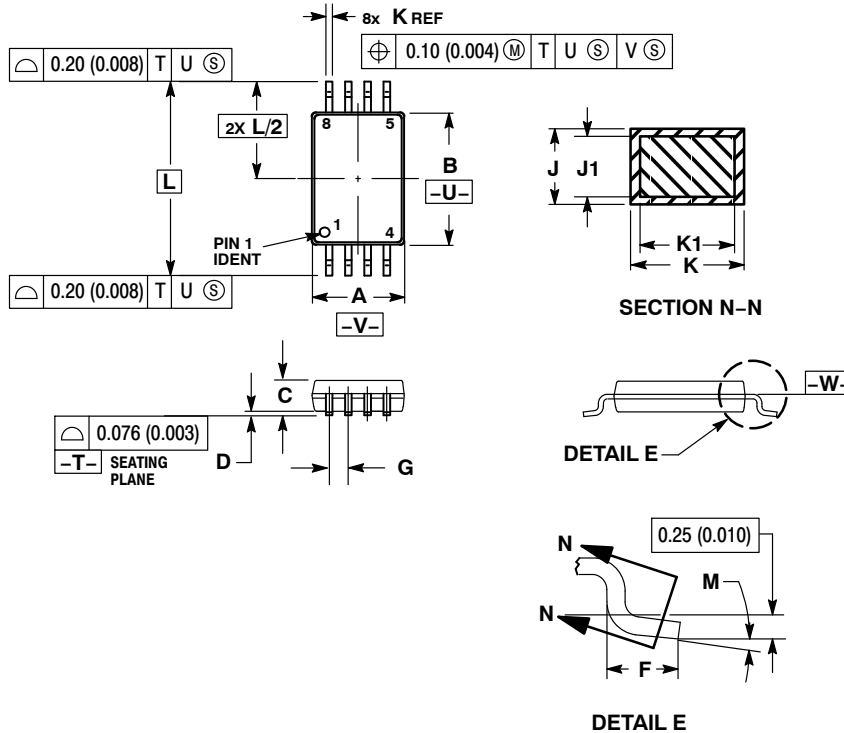
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SCALE 2:1

TSSOP-8  
CASE 948S-01  
ISSUE C

DATE 20 JUN 2008

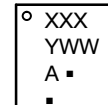


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	4.30	4.50	0.169	0.177
C	---	1.10	---	0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.70	0.020	0.028
G	0.65 BSC		0.026 BSC	
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

GENERIC  
MARKING DIAGRAM\*



- XXX = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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DESCRIPTION:	TSSOP-8	PAGE 1 OF 2



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